

 R_{θJA}
 Thermal Resistance, Junction-to-Ambient *
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 * When mounted on the minimum pad size recommended (PCB Mount)
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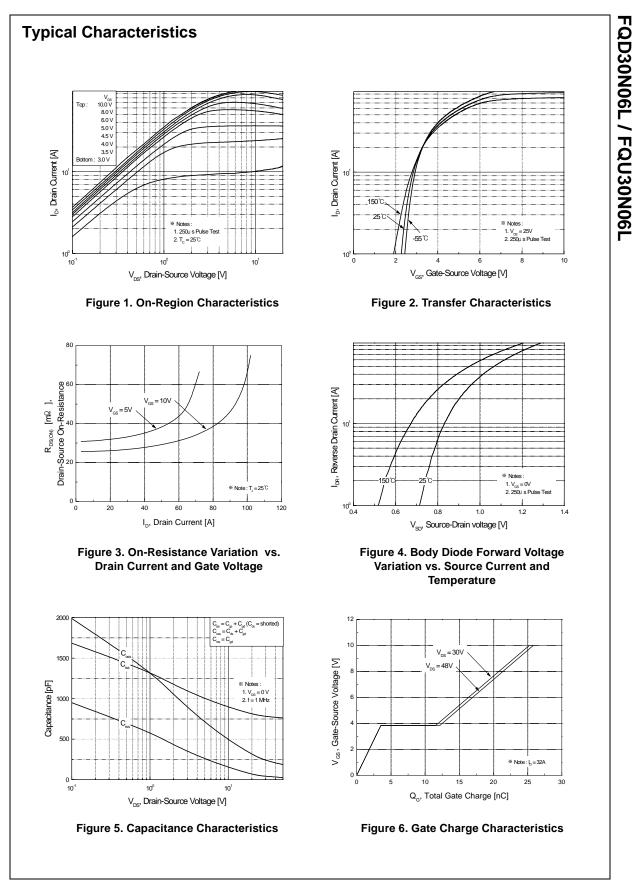
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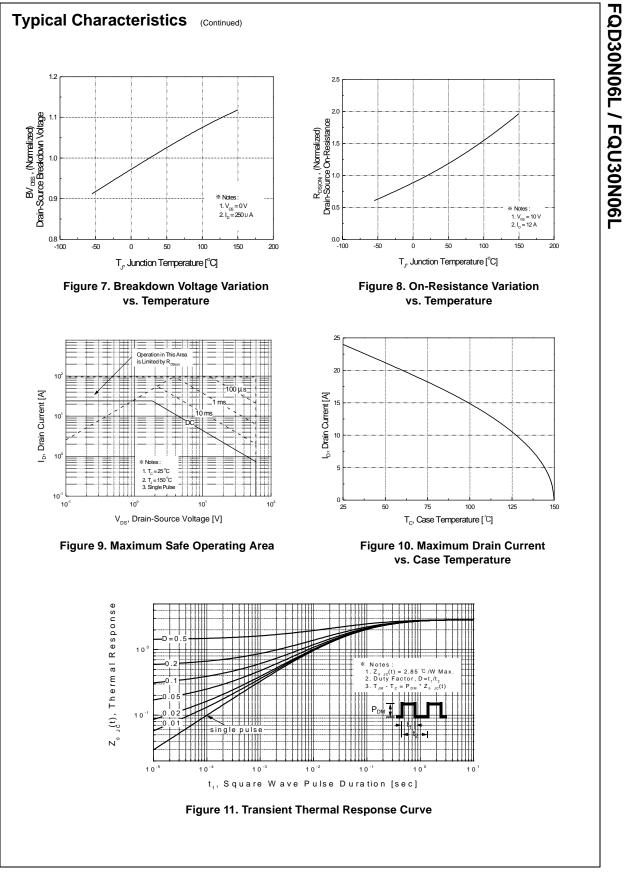
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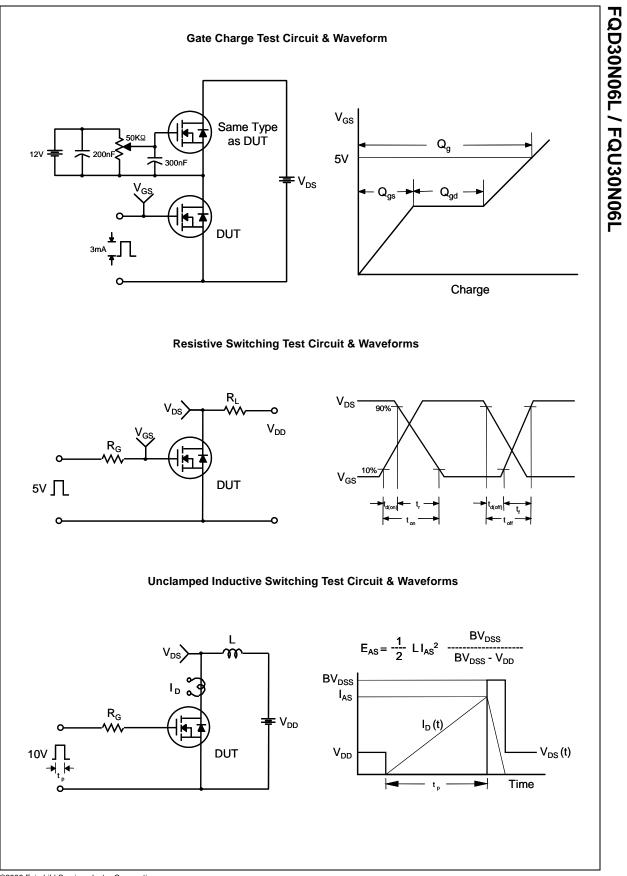
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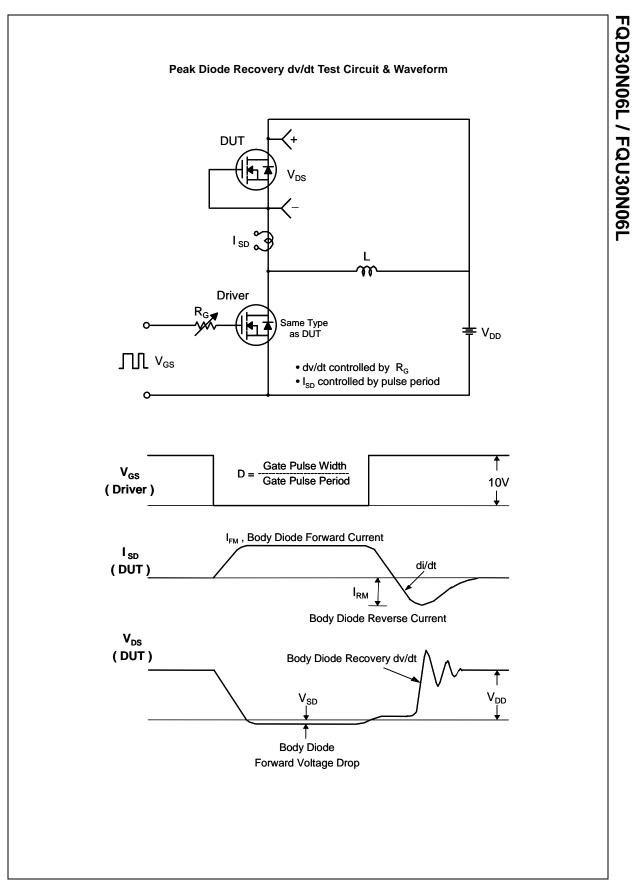
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	60			V
ΔBV _{DSS} ΔΔΤ _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu$ A, Referenced to 25°C		0.07		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA
		V _{DS} = 48 V, T _C = 125°C			10	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
On Cha	ractoristics					
/ _{GS(th)}	racteristics Gate Threshold Voltage	V _{DS} = 5 V, I _D = 250 μA	1.0		2.5	V
	Static Drain-Source	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$		0.031	0.039	v
R _{DS(on)}	On-Resistance	$V_{GS} = 5V, I_{D} = 12A$		0.031	0.039	Ω
JFS	Forward Transconductance	$V_{DS} = 25 \text{ V}, \text{ I}_{D} = 12 \text{ A}$ (Note 4)		23		S
10		50 , 5 (, , , ,				-
	c Characteristics	1	1	I		
Siss	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$		800	1040	pF
Soss	Output Capacitance	f = 1.0 MHz		270	350	pF
C _{rss}	Reverse Transfer Capacitance			50	65	pF
	ng Characteristics					
d(on)	Turn-On Delay Time	V _{DD} = 30 V, I _D = 16 A,		15	40	ns
r	Turn-On Rise Time	R _G = 25 Ω		210	430	ns
d(off)	Turn-Off Delay Time			55	120	ns
f	Turn-Off Fall Time	(Note 4, 5)		110	230	ns
ζ ^g	Total Gate Charge	$V_{DS} = 48 \text{ V}, I_{D} = 32 \text{ A},$		15	20	nC
2 _{gs}	Gate-Source Charge	$V_{GS} = 5 V$		3.5		nC
⊋ _{gd}	Gate-Drain Charge	(Note 4, 5)		8.5		nC
Drain-S	ource Diode Characteristics ar	nd Maximum Ratings				
S	Maximum Continuous Drain-Source Dic	V			24	А
SM	Maximum Pulsed Drain-Source Diode F	imum Pulsed Drain-Source Diode Forward Current			96	А
/ _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 24 A$			1.5	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_F = 32 A,$		55		ns
ک ^{رر}	Reverse Recovery Charge	$dI_{F} / dt = 100 \text{ A}/\mu \text{s}$ (Note 4)		80		nC
Q_{rr} Repetitive R L = 0.8mH, I I _{SD} \leq 32A, o Pulse Test :	Reverse Recovery Charge ating : Pulse width limited by maximum junction temper $A_{S} = 24A$, $V_{DD} = 25V$, $R_{G} = 25 \Omega$, Starting $T_{J} = 25^{\circ}C$ M_{J} ($M_{J} \leq 300$ Mus, $V_{DD} = 8V_{DSS}$, Starting $T_{J} = 25^{\circ}C$ Pulse width ≤ 300 us, Duty cycle $\leq 2\%$ adependent of operating temperature	$dI_F / dt = 100 \text{ A}/\mu \text{s}$ (Note 4)		80		nC

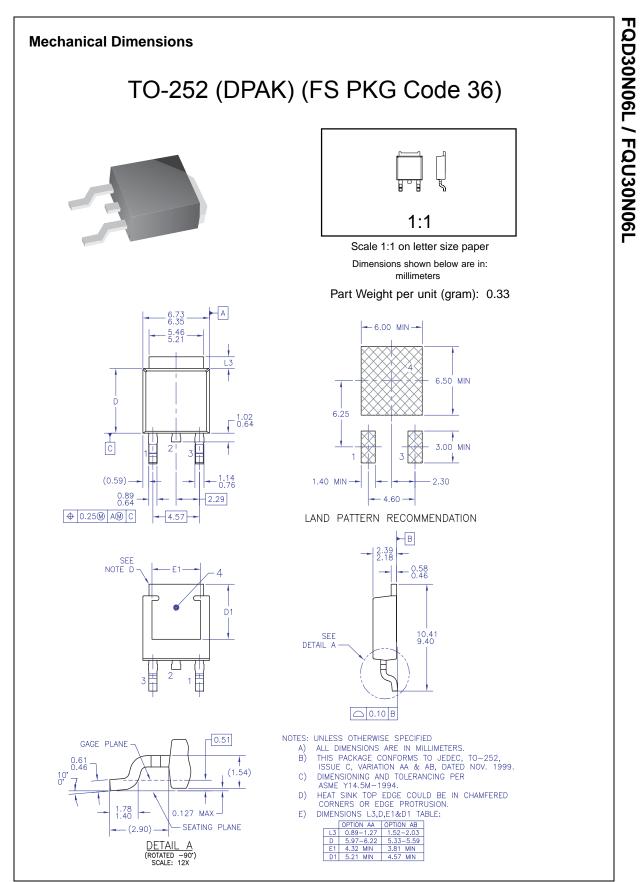
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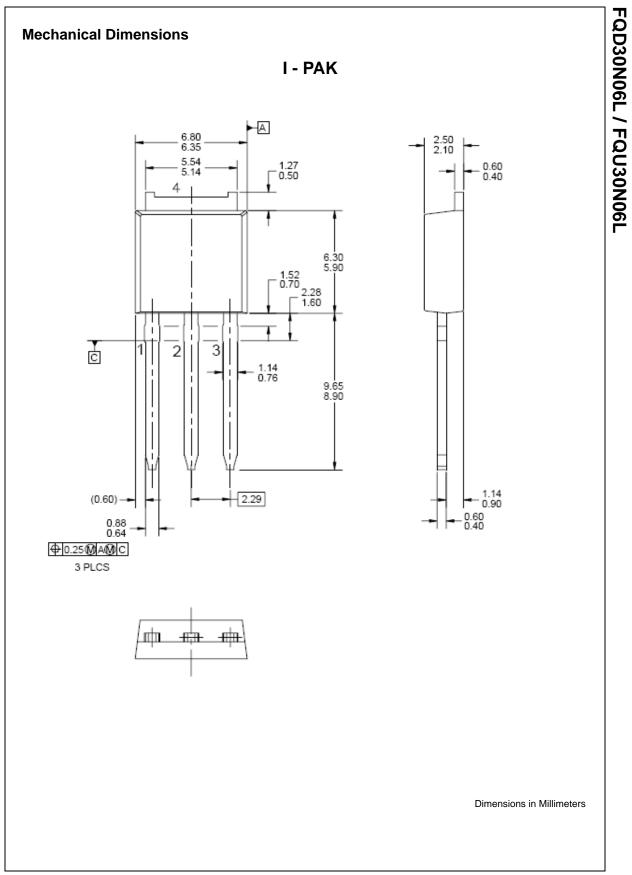














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